

Device Selection Guide

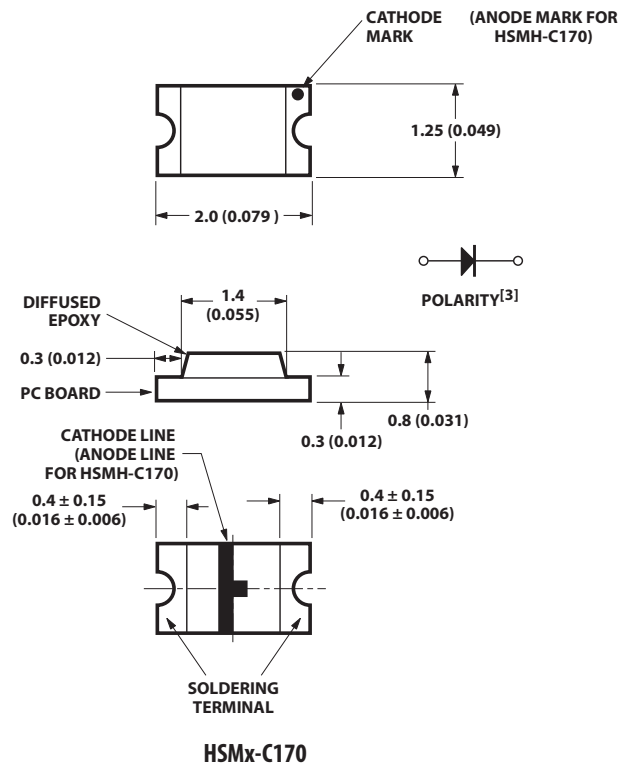
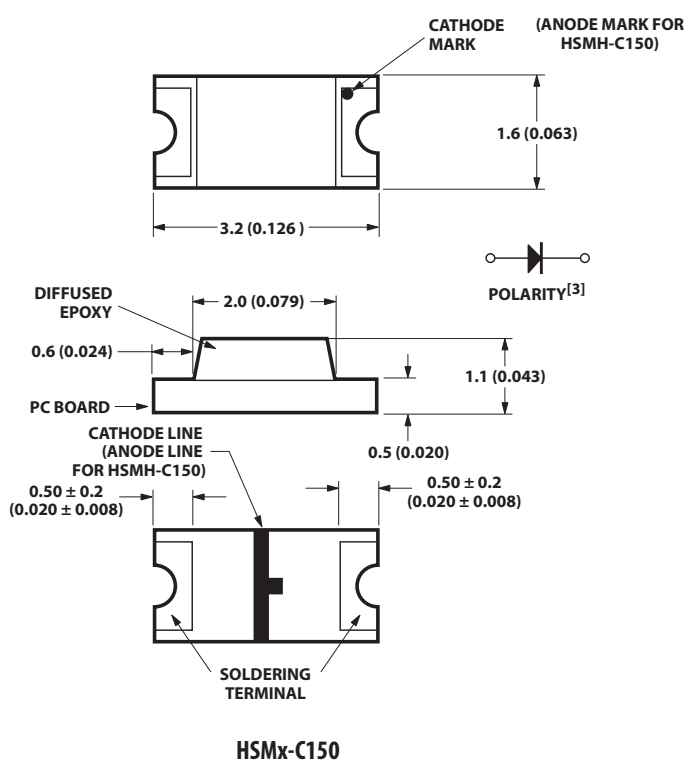
GaP

Green	HER	Orange	Yellow	Description
HSMG-C110	HSMS-C110	HSMD-C110	HSMY-C110	Untinted, Non-Diffused
HSMG-C120	HSMS-C120	HSMD-C120	–	Untinted, Non-Diffused
HSMG-C150	HSMS-C150	HSMD-C150	HSMY-C150	Untinted, Diffused
HSMG-C170	HSMS-C170	HSMD-C170	HSMY-C170	Untinted, Diffused
HSMG-C177	HSMS-C177	HSMD-C177	HSMY-C177	Untinted, Diffused
HSMG-C190	HSMS-C190	HSMD-C190	HSMY-C190	Untinted, Diffused
HSMG-C191	HSMS-C191	HSMD-C191	HSMY-C191	Untinted, Diffused
HSMG-C197	HSMS-C197	HSMD-C197	HSMY-C197	Untinted, Diffused
HSMG-C265	–	–	–	Untinted, Non-Diffused

As AlGaAs

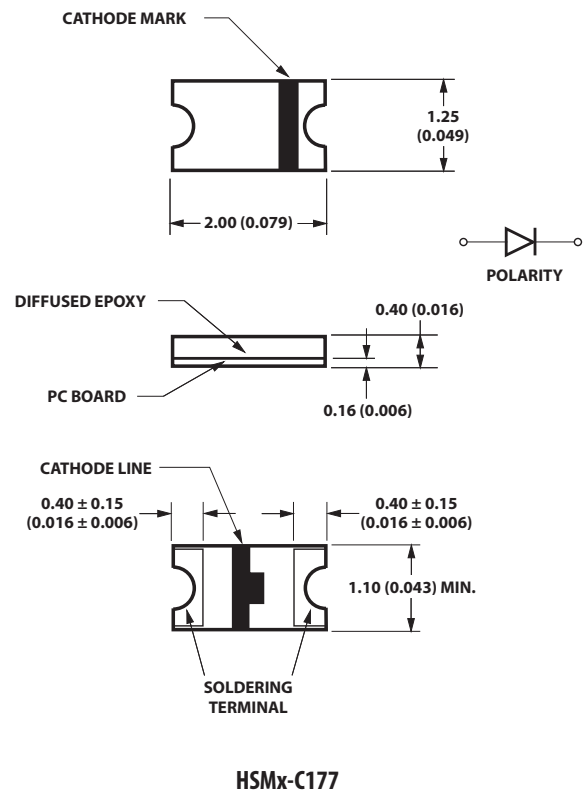
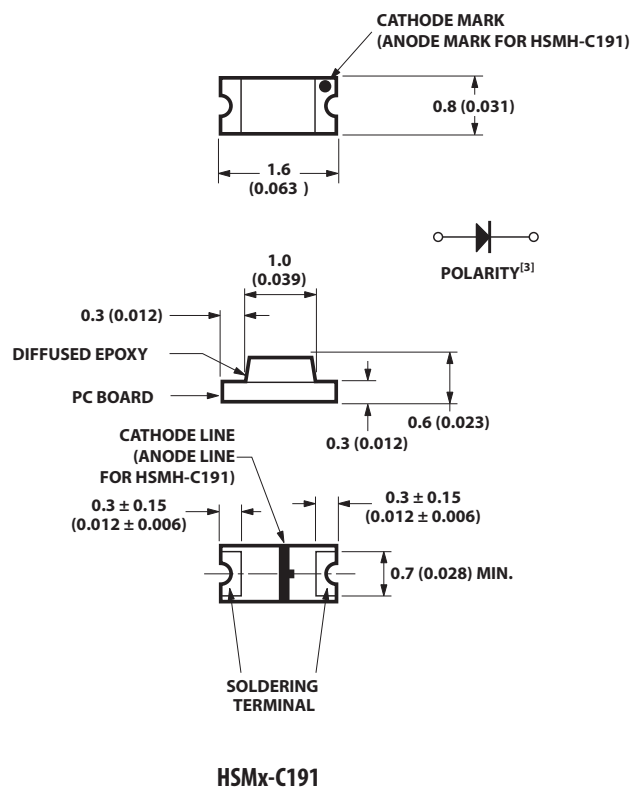
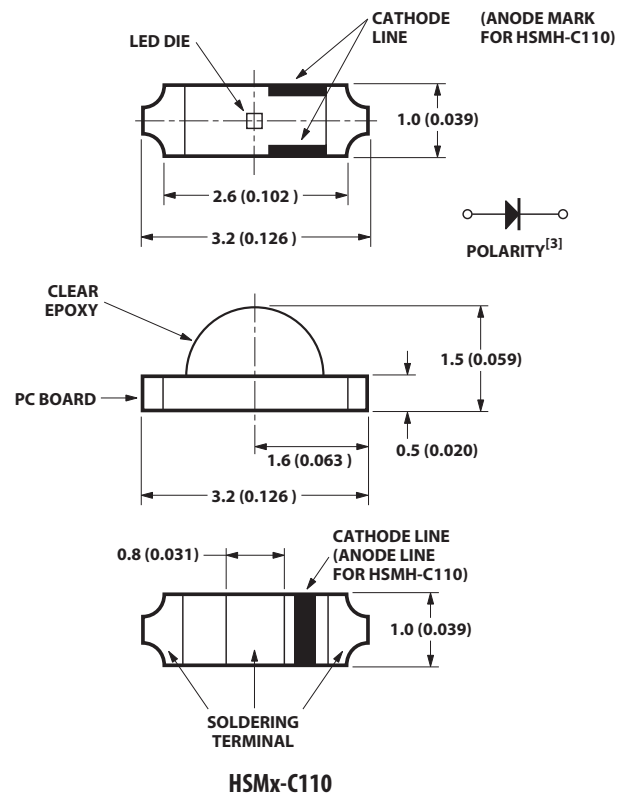
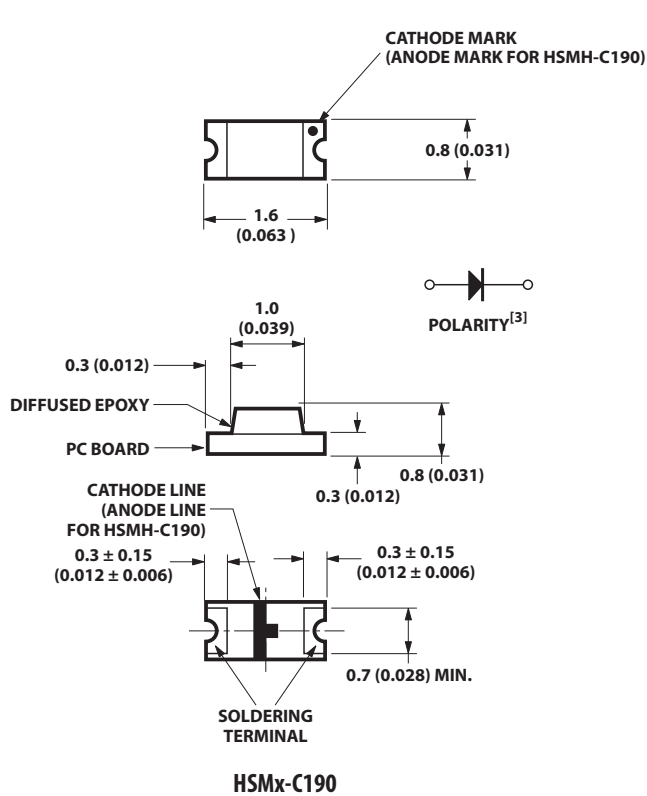
Red	Description
HSMH-C110	Untinted, Non-Diffused
HSMH-C120	Untinted, Non-Diffused
HSMH-C150	Untinted, Diffused
HSMH-C170	Untinted, Diffused
HSMH-C190	Untinted, Diffused
HSMH-C191	Untinted, Diffused
HSMH-C265	Untinted, Non-Diffused

Package Dimensions



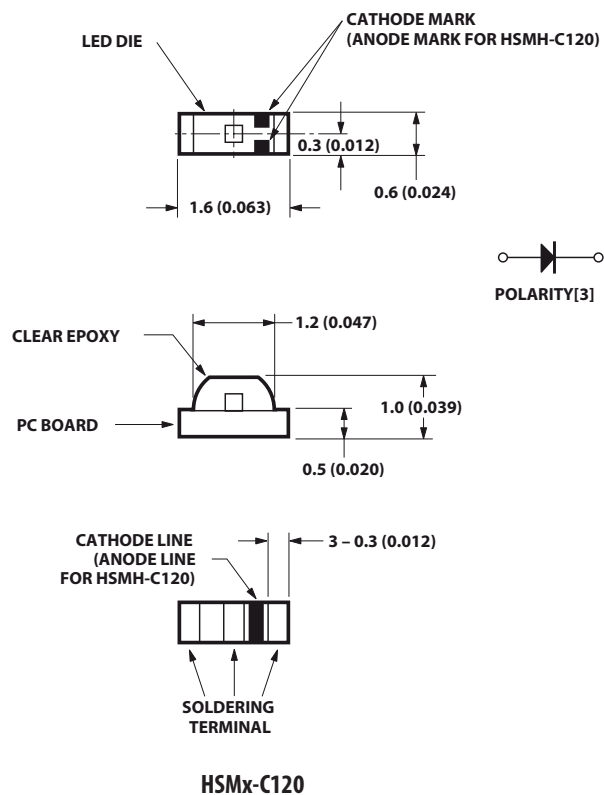
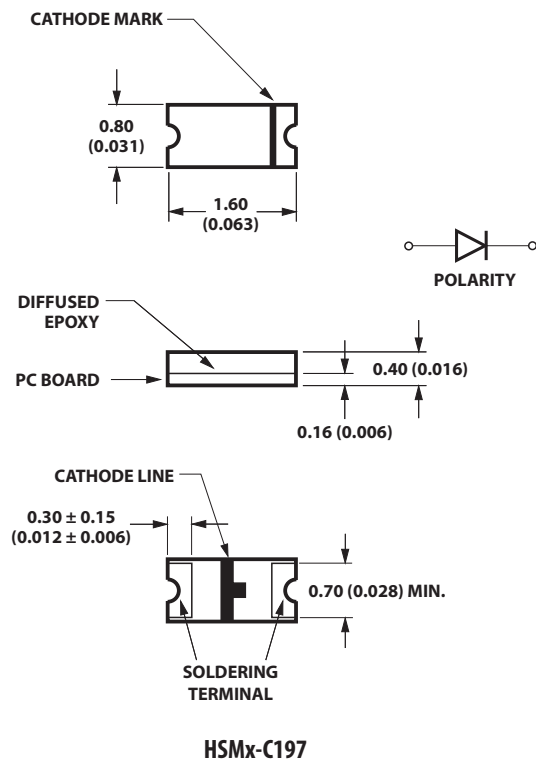
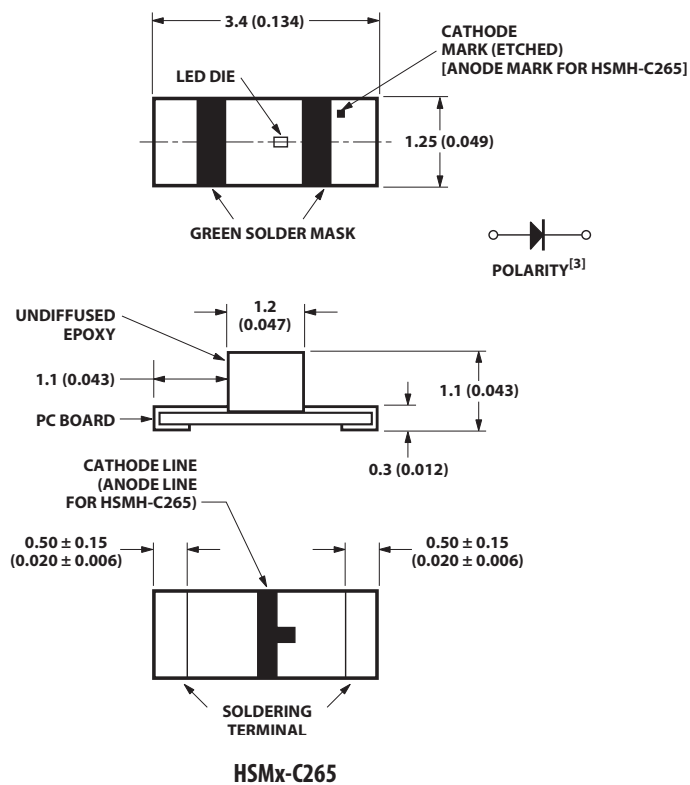
Notes:

1. All dimensions in millimeters (inches).
2. Tolerance is ±0.1 mm (±0.004 in.) unless otherwise specified.
3. Polarity for HSMH-Cxxx will be the opposite of what is shown on above drawings.



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Absolute Maximum Ratings for GaP at T_A=25°C

Parameter	C110/150/265	C120/170/177/190/191/197	Units
DC Forward Current ^[1]	25	20	mA
Power Dissipation	65	52	mW
Reverse Voltage (I _R =100 µA)	5	5	V
LED Junction Temperature	95	95	°C
Operating Temperature Range	-40 to +85	-40 to +85	°C
Storage Temperature Range	-40 to +85	-40 to +85	°C
Soldering Temperature	See reflow soldering profile (Figure 9 & 10)		

Absolute Maximum Ratings for AlGaAs at T_A=25°C

Parameter	C110/150	C120/170/190/191/265	Units
DC Forward Current ^[1]	30	25	mA
Power Dissipation	78	65	mW
Reverse Voltage (I _R =100µA)	5	5	V
LED Junction Temperature	95	95	°C
Operating Temperature Range	-40 to +85	-40 to +85	°C
Storage Temperature Range	-40 to +85	-40 to +85	°C
Soldering Temperature	See reflow soldering profile (Figure 9 & 10)		

Note:

1. Derate linearly as shown in Figure 4 for temperature above 25°C.

Electrical Characteristics at T_A=25°C

Part Number	Color	Forward Voltage V _F (Volts) @ I _F = 20 mA		Reverse Breakdown V _R (Volts) @ I _R = 100 µA	Capacitance C(pF), @ V _F = 0 V, f = 1 MHz	Thermal Resistance R _{θJ-P} (°C/W)
		Typ.	Max.	Min.	Typ.	Typ.
HSMS-C110/150	HER	2.1	2.6	5	5	400
HSMS-C120						350
HSMS-C170/177/190/191/197						250
HSMD-C110/150	Orange	2.2	2.6	5	7	400
HSMD-C120						350
HSMD-C170/177/190/191/197						250
HSMY-C110/150	Yellow	2.1	2.6	5	6	400
HSMY-C170/177/190/191/197						250
HSMG-C110/150	Green	2.2	2.6	5	9	400
HSMG-C120						350
HSMG-C170/177/190/191/197/265						250
HSMH-C110/150	AlGaAs	1.8	2.6	5	18	460
HSMH-C120						400
HSMH-C170/190/191/265						300

Optical Characteristics at T_A=25°C

Part Number	Color	Luminous Intensity ^[1] I _v (mcd)@20mA		Peak Wavelength λ _{peak} (nm)	Dominant Wavelength λ _d (nm)	Viewing Angle 2θ _{1/2} (°) ^[2]
		Min.	Typ.	Typ.	Typ.	Typ.
HSMG-C110/177/197	Green	4.5	15.0	570	572	130
HSMG-C120						155
HSMG-C150/170/190/191/265						170
HSMS-C110/177/197	HER	2.8	10.0	630	626	130
HSMS-C120						155
HSMS-C150/170/190/191						170
HSMD-C110/177/197	Orange	2.8	8.0	605	604	130
HSMD-C120						155
HSMD-C150/170/190/191						170
HSMY-C110/177/197	Yellow	2.8	8.0	589	586	130
HSMY-C150/170/190/191						170
HSMH-C110	AlGaAs	7.2	17.0	660	639	130
HSMH-C120						155
HSMH-C150/170/190/191/265						170

Notes:

1. The luminous intensity, I_v, is measured at the peak of the spatial radiation pattern, which may not be aligned with the mechanical axis of the lamp package.
2. θ_{1/2} is the off-axis angle where the luminous intensity is 1/2 the peak intensity.

Color Bin Limits^[1]

Green Color Bins^[1]

Bin ID	Dom. Wavelength (nm)	
	Min.	Max.
A	561.5	564.5
B	564.5	567.5
C	567.5	570.5
D	570.5	573.5
E	573.5	576.5

Tolerance: ±1 nm

Yellow Color Bins^[1]

Bin ID	Dom. Wavelength (nm)	
	Min.	Max.
A	582.0	584.5
B	584.5	587.0
C	587.0	589.5
D	589.5	592.0
E	592.0	594.5
F	594.5	597.0

Tolerance: ±1 nm

Orange Color Bins^[1]

Bin ID	Dom. Wavelength (nm)	
	Min.	Max.
A	597.0	600.0
B	600.0	603.0
C	603.0	606.0
D	606.0	609.0
E	609.0	612.0
F	612.0	615.0

Tolerance: ±1 nm

Light Intensity (Iv) Bin Limits^[1]

Bin ID	Intensity (mcd)		Bin ID	Intensity (mcd)	
	Min.	Max.		Min.	Max.
A	0.11	0.18	N	28.50	45.00
B	0.18	0.29	P	45.00	71.50
C	0.29	0.45	Q	71.50	112.50
D	0.45	0.72	R	112.50	180.00
E	0.72	1.10	S	180.00	285.00
F	1.10	1.80	T	285.00	450.00
G	1.80	2.80	U	450.00	715.00
H	2.80	4.50	V	715.00	1125.00
J	4.50	7.20	W	1125.00	1800.00
K	7.20	11.20	X	1800.00	2850.00
L	11.20	18.00	Y	2850.00	4500.00
M	18.00	28.50			

Tolerance: $\pm 15\%$

Note:

1. Bin categories are established for classification of products. Products may not be available in all categories. Please contact your Avago representative for information on currently available bins.
2. The Iv binning specification set-up is for lowest allowable Iv binning only. There is no upper Iv bin limits.

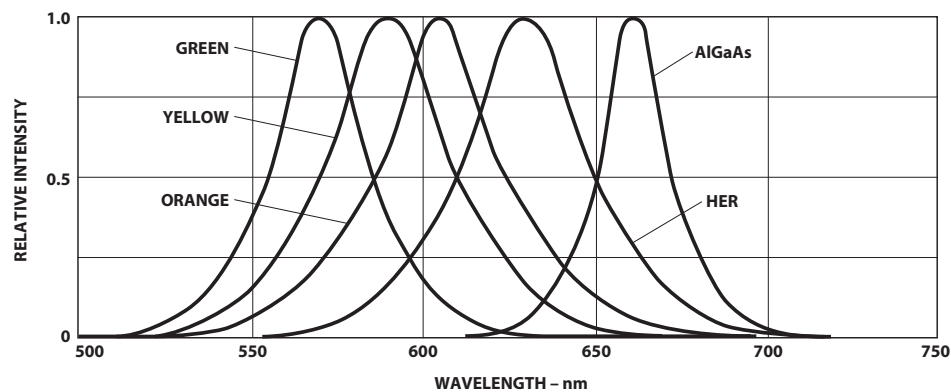


Figure 1. Relative intensity vs. wavelength.

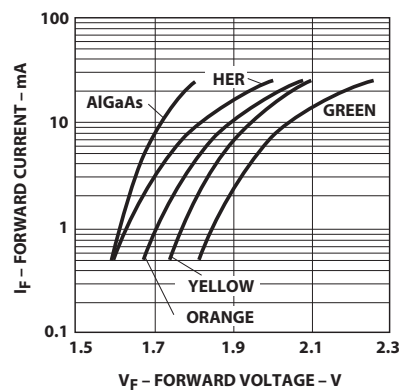


Figure 2. Forward current vs. forward voltage.

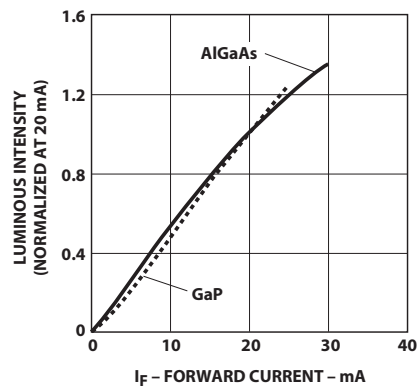


Figure 3. Luminous intensity vs. forward current.

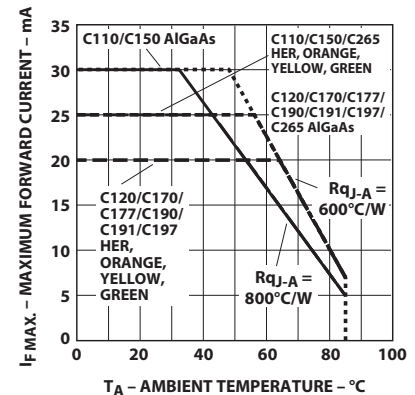


Figure 4. Maximum forward current vs. ambient temperature.

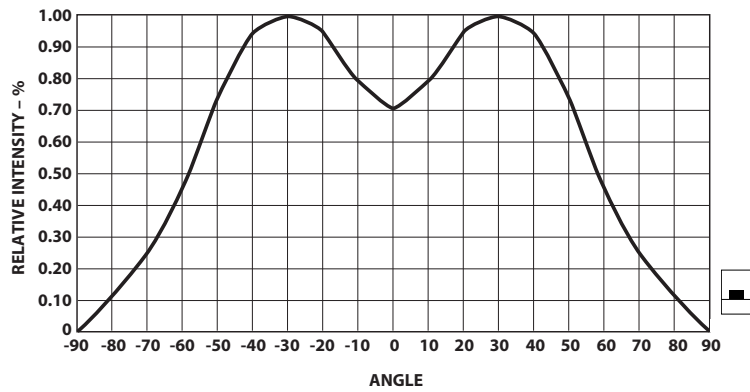
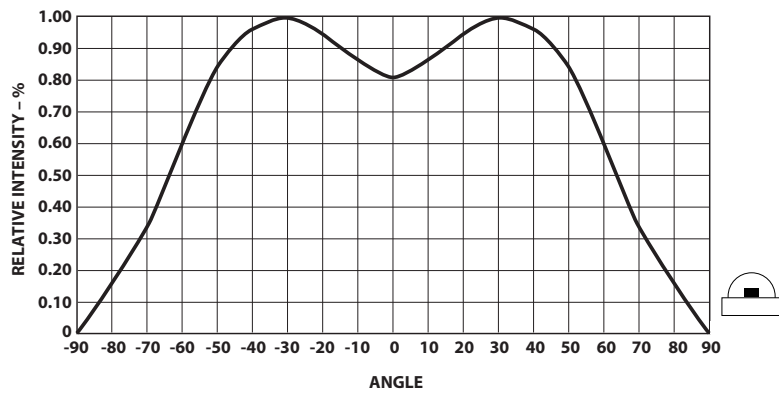


Figure 5. Relative intensity vs. angle for HSMx-C110.

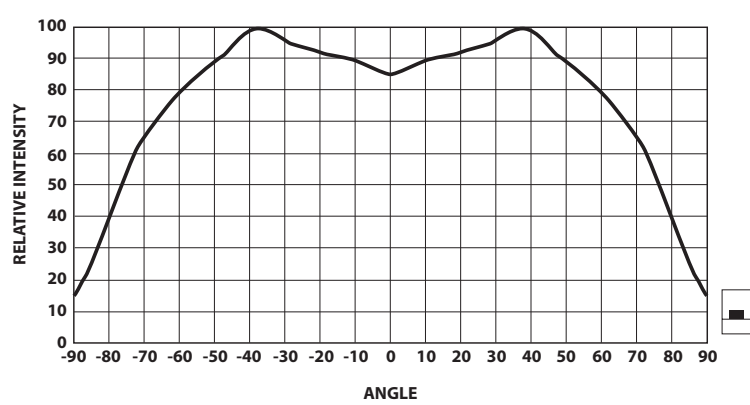
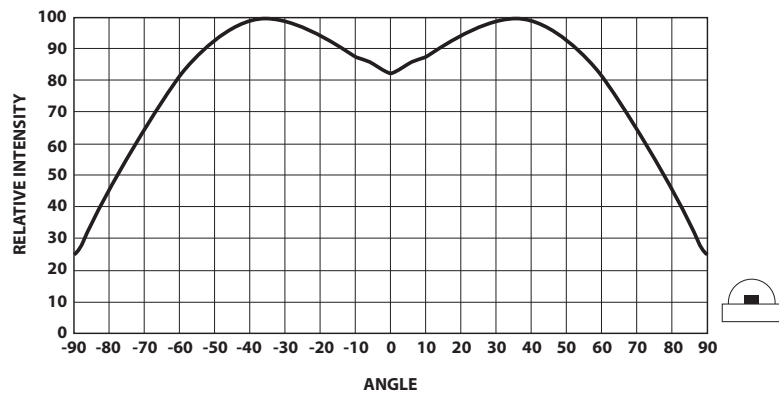


Figure 6. Relative intensity vs. angle for HSMx-C120.

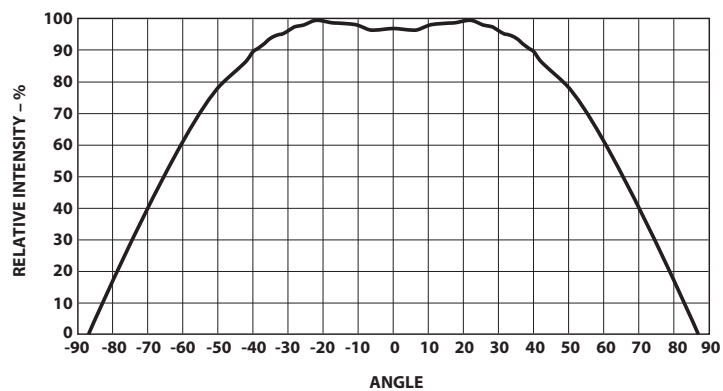


Figure 7. Relative intensity vs. angle for HSMx-C177 and C197.

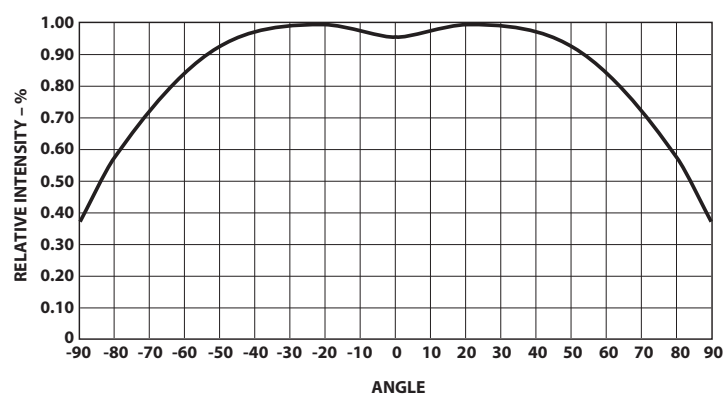


Figure 8. Relative intensity vs. angle for HSMx-C150, C170, C190, C191 and C265.

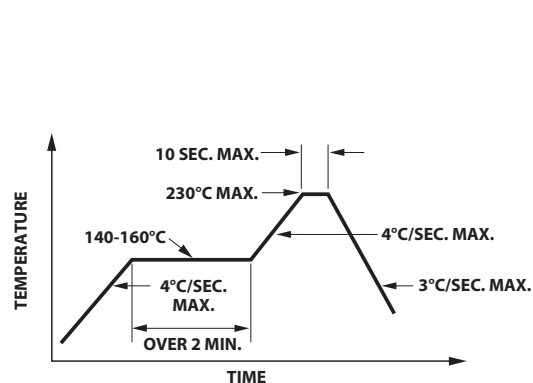


Figure 9. Recommended reflow soldering profile.

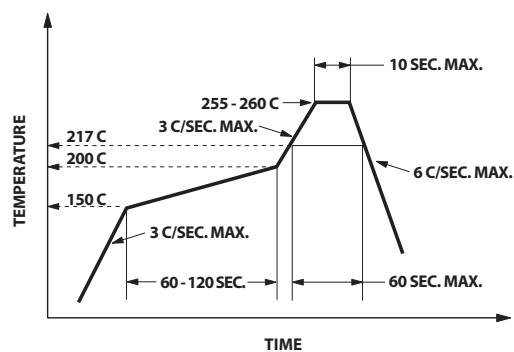


Figure 10. Recommended Pb-free reflow soldering profile.

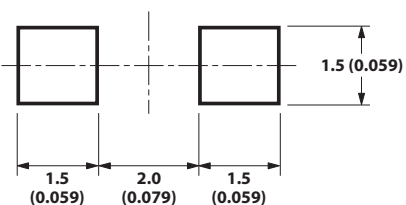


Figure 11. Recommended soldering pattern for HSMx-C150.

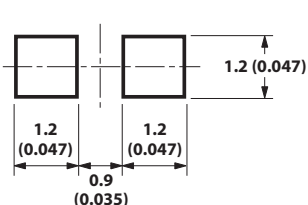


Figure 12. Recommended soldering pattern for HSMx-C170 and C177.

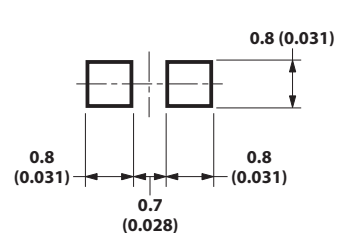


Figure 13. Recommended soldering pattern for HSMx-C190, C191 and C197.



Note: All dimensions in millimeters (inches).

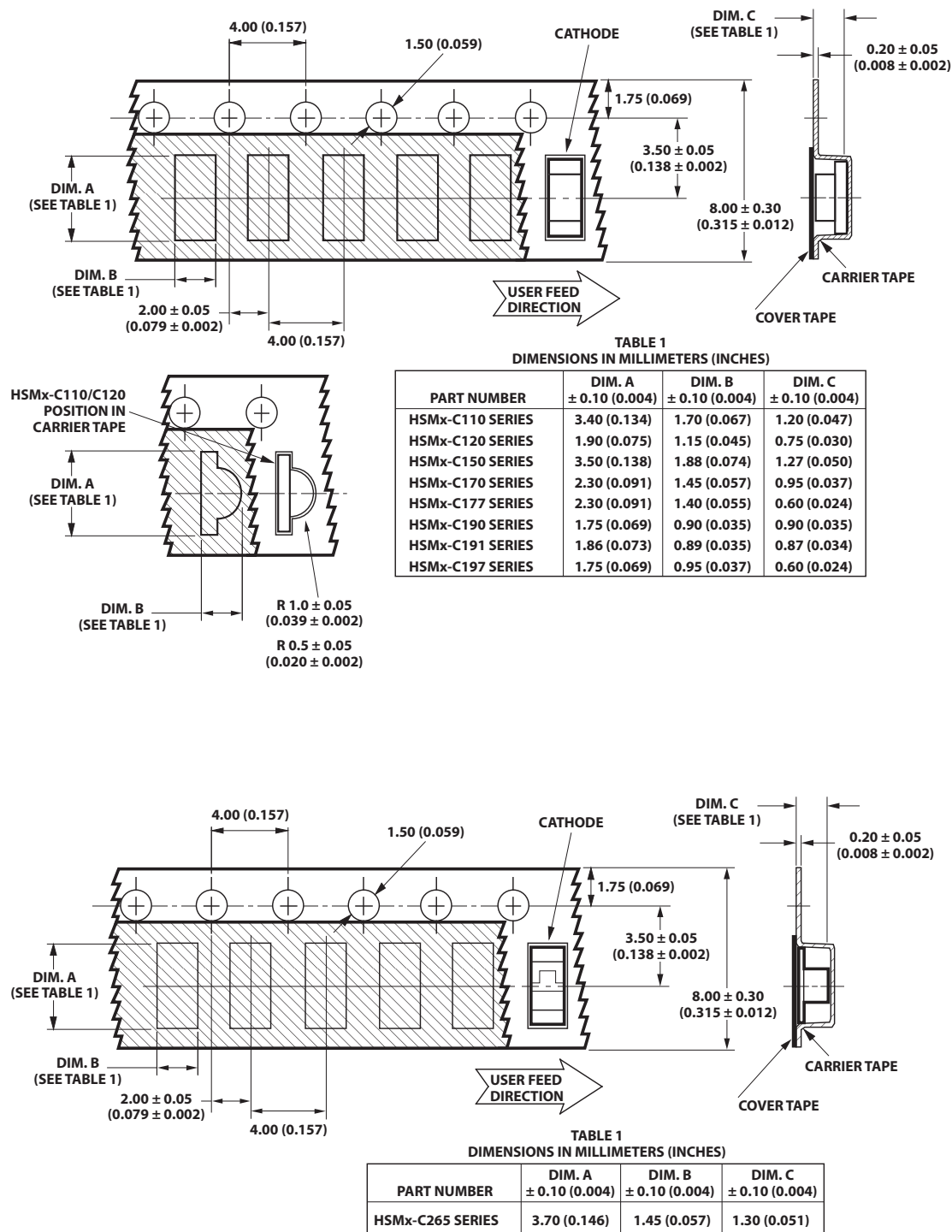


Figure 19. Tape dimensions.

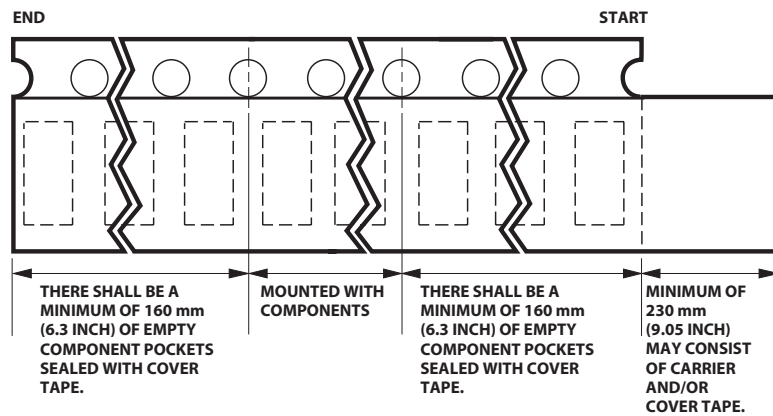


Figure 20. Tape leader and trailer dimensions.

Notes:

1. All dimensions in millimeters (inches).
2. Tolerance is ± 0.1 mm (± 0.004 in.) unless otherwise specified.

Storage Condition: 5 to 30° C
@ 60% RH max.

Baking is required under the condition:

- a) Humidity Indicator Card is
>10% when read at $23 \pm 5^{\circ}\text{C}$.
- b) Device exposed to factory conditions <30°C/60% RH more than 672 hours.

Baking recommended condition: 60
+/- 5°C for 20 hours.

Convective IR Reflow Soldering

For more information on IR reflow soldering, refer to Application Note 1060, *Surface Mounting SMT LED Indicator Components*.

For product information and a complete list of distributors, please go to our website: www.avagotech.com

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